

# Experimental report

10/09/2019

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**Council:** 4/2018

**Title:** Layer Integrity in Composite Magnetolectric Thin Film Stacks Studiedby Polarized Neutron Reflectivity

**Research area:** Materials

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**Samples:** NiFe<sub>2</sub>O<sub>4</sub> on LAO

Instrument	Requested days	Allocated days	From	To
SUPERADAM	7	5	20/10/2018 20/07/2019	22/10/2018 23/07/2019

## Abstract:

We propose to use specular polarized neutron reflectometry (PNR) to study the structural and magnetic integrity of the ferromagnetic component in composite magnetolectric multilayer stacks. The stacks consist of a varying number of layers of ferromagnetic NiFe<sub>2</sub>O<sub>4</sub> and ferroelectric (K,Na)NbO<sub>3</sub> (KNN), deposited by atomic layer deposition (ALD). The thickness of the individual layers are from 5 - 20 nm.

The samples are made to study magnetolectric coupling in composites of magnetostrictive/ferromagnetic and ferro-/piezoelectrics. This is an alternate way of producing multiferroic materials systems that can have enhanced properties compared to single-phase multiferroic materials, where either the magnetic- or electric response is too low for application.

A crucial parameter in a composite system such as this is the integrity of the individual layers, both magnetically and morphologically.

How are the magnetic layers ordered in relation to each other? How defined is the morphology of the interfaces between the layers? These are questions we hope to answer by this PNR-study.

# Layer Integrity in Composite Magnetolectric Thin Film Stacks Studied by Polarized Neutron Reflectivity

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In this study we have investigated the magnetic properties of NiFe<sub>2</sub>O<sub>4</sub> thin films deposited by atomic layer deposition (ALD) on various substrates. Polarized neutron reflectometry (PNR) at SuperADAM @ ILL was used to probe the magnetic properties of the thin films and to investigate the interface region towards the substrates. Our investigations show that the thin films are of high quality, with low roughness, and with expected magnetic properties, Figure 1. We found a one-layered model to best describe our samples, indicating a homogenous magnetization through the films, Figure 2. Further, the magnetic properties was observed to vary with substrate and orientation. These properties are for some samples listed in Table 1. Especially the good magnetic properties of (111)-orientated NiFe<sub>2</sub>O<sub>4</sub> on (001)-orientated Al<sub>2</sub>O<sub>3</sub> is an influential result for our coming research. In addition, we conducted field scans near the critical edge where the *uu*- and *dd*-splitting is most prominent to determine the cohesive field and the remanence of the magnetic thin films, Figure 3. The results from this beamtime is of great value for our research towards magnetolectric thin film stacks, and will serve as input for design of future model systems. We also expect to publish these results in a soon upcoming paper detailing the magnetic properties of ALD NiFe<sub>2</sub>O<sub>4</sub> epitaxial films.

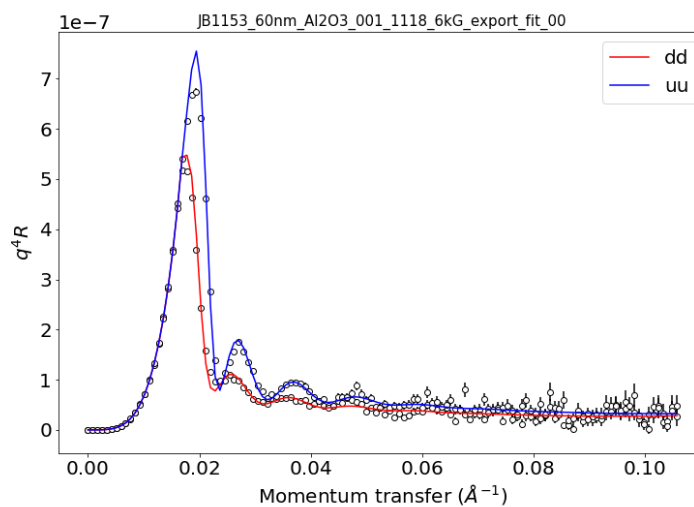


Figure 1: Fitted PNR profile of 60 nm NiFe<sub>2</sub>O<sub>4</sub> on (001)-orientated Al<sub>2</sub>O<sub>3</sub>.

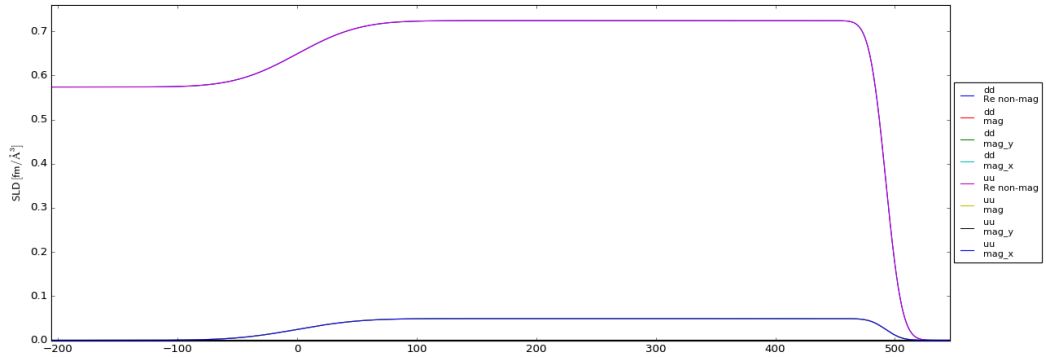


Figure 2: SLD profile of 60 nm NiFe<sub>2</sub>O<sub>4</sub> on (001)-orientated Al<sub>2</sub>O<sub>3</sub> from PNR profile fitting.

Table 1: Extracted magnetic assets of magnetic NiFe<sub>2</sub>O<sub>4</sub> thin films with various thickness. Magnetization under various fields are given in  $\mu_B$  per atom. \* indicate values from field scan.

Thickness	60 nm	60 nm	60nm	11nm
Substrate	Al <sub>2</sub> O <sub>3</sub>	Al <sub>2</sub> O <sub>3</sub>	MgO	Al <sub>2</sub> O <sub>3</sub>
Orientation	(001)	(012)	(001)	(001)
6000 G	1.34	1.36	0.32	0.62
50 G	0.81		0.01	
230 G	0.56			
270 G		0.14		
Coercive field	230 G	270 G		
Remanence	60 %, (81 %)*	(83 %)*	3 %	

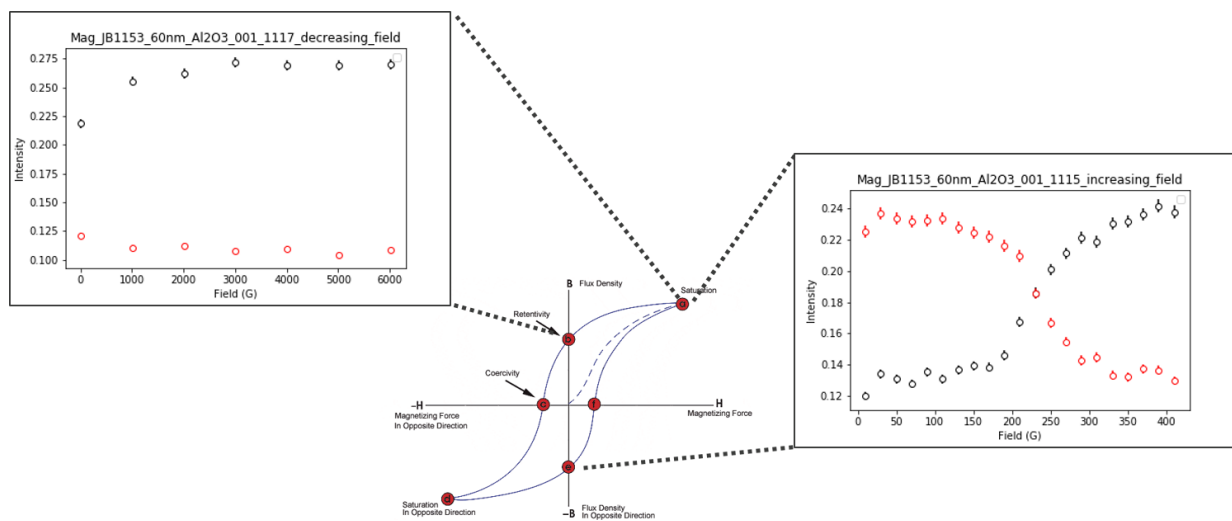


Figure 3: Illustration of conducted magnetization scans to determine the cohesive field and remanence of the samples. The figures shows measured data for 60 nm NiFe<sub>2</sub>O<sub>4</sub> on (001)-orientated Al<sub>2</sub>O<sub>3</sub>.